N um erical calculation of the Landauer conductance through an interacting electron system in the Hartree-Fock approximation

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We develop a new numerical method to calculate the Landauer conductance through an interacting electron system in the rst order perturbation or in the self-consistent Hartree-Fock approximation. It is applied to one and two dimensional systems with nearest-neighbor electron-electron interaction.

KEYW ORDS: Landauer conductance, electron-electron interaction, Hartree Fock approximation

1. Introduction

The interplay between disorder and electron-electron interaction in quantum electron transport phenom ena is one of the most challenging problem s. A lthough the non-interacting approximation successfully explains many aspects of experiments,¹ we may need to take into account the electron-electron interaction to understand some phenom ena, such as the metallic behavior in two dimensional (2D) systems in SiMOS and heterostructures,² and the critical phenom ena of the 3D metal-insulator transitions.³ In theoretical works, in portant corrections due to electron-electron interaction in disordered electron systems were found.⁴⁽⁸⁾ Furtherm ore, the study of the nonlinear model suggested new universality classes for the metal-insulator transition.⁹

The Hartree-Fock (HF) approximation was employed in some numerical works to study interacting disordered electron system s.^{10{18} It enables us to simulate relatively large system s. Even at the level of the HF approximation, however, our understanding is not yet complete. One of the reasons is the lack of numerical simulations of the Landauer conductance. As used in the scaling theory of Anderson localization¹⁹ (See Refs. 20{22 for more detailed discussions on the scaling hypothesis of the Landauer conductance.), the conductance is one of the most important physical quantities to characterize a disordered electron system .We expect that numerical simulation of the Landauer conductance would improve our understanding on the interplay between disorder and electron-electron interaction.

M otivated by this, we have decided to perform a num erical calculation of the Landauer conductance in interacting disordered electron systems in the HF approxim ation. As a rst step toward it we have developed a num ericalm ethod, which we report here.

The generalization of the Landauer approach to interacting electron systems is a very active topic not only to study interacting disordered electron system s but also to study transport phenom ena through low dim ensional electron system s.A lthough m uch progress has been m ade in the generalization of the Landauer approach,²³⁽³⁶ the calculation m ethod is still being in proved.

This paper is organized as follows: In x 2 the model considered is described and in x 3 the Landauer form ula

is described. The HF approximation is described in x 4. In x 5, we explain a new numerical method, which we call wide band method. In x 6 and x 7, we apply the wide band method to 1D and 2D systems of interacting electrons. The last section is devoted to summary and discussion.

2. M odel

We consider spinless electrons on a 2D square lattice. As illustrated in Fig. 1, the system considered consists of a sample region with size $L_s = L_y$ (denoted by S) and two sem i-in nite leads with width L_y (denoted by L). We impose that electrons in the transverse direction. We suppose that electrons are interacting in the sample region, while non-interacting in the lead region. In the present paper we do not consider random potential for simplicity. We take the x direction as the current direction and y direction as the transverse direction.

The tight binding H am iltonian is given by

$$H = H_{s} + H_{s} + H_{s} + H_{u}; \qquad (1)$$

where H $_{\rm s}$ is the non-interacting part for the sam ple region S, H \cdot the H am iltonian for the perfect leads at the left and right, H $\cdot_{\rm s}$ the coupling between the sam ple and leads, and H $_{\rm u}$ electron-electron interaction in the sam ple region. They are given by

$$H_{s} = t_{s} C_{ij}^{y}C_{j}; \qquad (2)$$

$$H_{\star} = t_{\star} \sum_{\substack{i_{j} \neq i_{j} \neq L}}^{X} C_{i}^{y} C_{j}; \qquad (3)$$

$$H_{vs} = t_{vs} \overset{X_{y}}{\underset{y=1}{\overset{Y}{\underset{x}}} c_{0_{iy}}^{y} c_{1_{iy}} + c_{1_{iy}}^{y} c_{0_{iy}}$$
$$\underbrace{t_{vs}}_{y=1} \overset{X_{y}}{\underset{y=1}{\overset{Y}{\underset{x}}} c_{1_{s,iy}}^{y} c_{1_{s+1,iy}} + c_{1_{s+1,iy}}^{y} c_{1_{s,iy}} ; (4)$$
$$H_{u} = \frac{1}{2} \overset{X}{\underset{i_{j}}{\overset{Y}{\underset{(i_{j}) \in S}{\overset{Y}{\underset{j}}}}} c_{1}^{y} c_{1} K U_{i_{j}j} c_{j}^{y} c_{j} K : (5)$$

Here $c_i^V(c_i)$ denotes the creation (annihilation) operator of an electron at the site i, $U_{i;j}$ is the interaction between



Fig. 1. An example of the Landauer geometry to calculate the two term inal conductance. Two non-interacting perfect leads are attached to the sample.

electrons at the sites i and j, and K is a positive uniform charge. Hopping is restricted to nearest-neighbors. We suppose that the hopping parameters t_s , t_r , and t_s are real, so the system has time reversal symmetry.

3. Landauer conductance

The Landauer conductance g at zero tem perature in the linear response regime is expressed using G reen's functions as

$$g = \frac{e^2}{h} tr^{(L)} () G^{a}_{1L_s} ()^{(R)} () G^{r}_{L_s 1} ()^{(R)} () G^{r}_{L_s 1} ()^{(R)} () G^{r}_{L_s 1} ()^{(R)} ($$

Here is the chem ical potential of the system, $G_{L_s1}^r$ and $G_{1L_s}^a$ the submatrices of the retarded and advanced G reen's functions in equilibrium, and (L;R) the matrices determined by the attached leads.²³ The matrices (L;R) are explicitly shown in Appendix.

It has been shown in Refs. 29 and 31 that the expression (6), which is well known for non-interacting electrons,²³ is valid even when electrons are interacting in the sample region at zero temperature. W ithin the HF approximation the expression (6) can also be justiled based on the Keldysh G reen's function method.²³

In the follow ing sections, we only consider the retarded G reen's function G^r since the advanced G reen's function G^a is sim ply H erm itian conjugate of the retarded G reen's function.

4. Hartree-Fock approxim ation

We describe the HF approximation in the Green's function form alism 37 for the system (1).

The D yson equation for G $^{\rm r}$ in the HF approximation is obtained by expanding the time ordered G reen's function in H $_{\rm u}$ and by performing an analytic continuation. We have

$$G^{r}() = G_{0}^{r}() + G_{0}^{r}()^{(HF)}G^{r}():$$
(7)

Here G_0^r is the retarded G reen's function for the noninteracting part of the H am iltonian H₀ = H_s + H₁ + H₁, and ^(HF) is the self-energy due to electron-electron interaction in the HF approximation, which is non-zero only in the sam ple region. It consists of H artree and exchange contributions:

$${}^{(HF)}_{i;j(ie j)} = \frac{U_{i;j}}{1} d \text{ Im } G^{r}_{i;j}(); \qquad (9)$$

where i; j 2 S. (In more general expression, $\text{Im } G^{r}()$ is replaced with (\doteq 2) [$G^{r}()$ $G^{a}()$]. For our model, they are the same.) From (7), we have

$$G^{r}() = H_{0}^{(HF)} + i$$
 (10)

Here H $_{\rm 0}$ is the single particle H am iltonian in the m atrix form corresponding to the non-interacting part H $_{\rm 0}$ and

is an in nitesim alpositive number. The HF self-energy (HF) is a solution of the self-consistent equations (8) { (10).

In practice there are two di culties we need to solve:

Since the Landauer geometry corresponds to an open system, the size of the matrix H_0 is in nite. We need to make the matrix size nite to perform num erical simulations.

To calculate the HF self-energy $\ ^{(\rm H\,F\,)}$, we need to perform an integral over .

The rst problem can be solved by taking account of the e ects of the sem i-in nite leads in terms of a self-energy.^{23,38{40} For example, if we expand the G reen's function in H $_{s}$ in addition to H $_{u}$, we obtain the D yson equation for the retarded G reen's function G $_{i;j}^{r}$ (i; j 2 S) in the HF approximation in a nite size matrix form that is closed in the sample region S. The G reen's function G $_{i;j}^{r}$, with i; j 2 S, is written as

$$G^{r}() = H_{s}^{(')r}()^{(HF)} + i^{(11)}$$

Here H_s is the single particle H am iltonian in the m atrix form corresponding to H_s, ^(HF) is the HF self-energy which is given by Eqs. (8) and (9), and ^{(')r} is the retarded self-energy due to the attached sem i-in nite leads. An element of the self-energy $\binom{(')r}{xy_{1}x_{2}y_{1}}$ is non-zero only when $x = x^{0} = 1$ or $x = x^{0} = L_{s}$. The non-zero elements are written as (see Appendix)

. ..

where X = 1 or L_s . The G reen's function $G_{i;j}^r$ (i; j 2 S) of (11) is exactly the same as that of (10) since we have taken into account allorders in H_{s} . Now in (11) the size of the matrices is nite, $L_s L_y = L_s L_y$, so it is possible to perform numerical calculations in principle.

As for the second problem, a num erical integration was employed in similar approaches.^{39,40} The num erical integration of the G reen's function is not very dicult if a simple system is considered. How ever the num erical integration is troublesome in general, so we have developed a m ethod to avoid it. The m ethod is explained in the next section.

5. W ide band m ethod

W e have developed a new m ethod, w hich we call wide band m ethod, to avoid the num erical integration as follows.

We change the system considered from the original Landauer system, illustrated in Fig.1, to another system as illustrated in Fig.2.We call it wide band system. The lead region is divided into two parts: the region C up to



Fig. 2. The system envisaged in the wide band method. Each non-interacting lead is divided into two regions C and W .

a length L_c on both sides of the sample, and the region W consisting of two sem i-in nite regions. The wide band system is described by the following H am iltonian,

$$H^{\sim} = H_{s} + H^{\sim} + H_{s} + H_{u} : \qquad (13)$$

Here H $_{\rm s}$, H $_{\rm s}$, and H $_{\rm u}$ are already given in (2), (4), and (5). The other term H $_{\rm s}$ for the leads is made of three term s

$$H^{\sim} = H_{c} + H_{w} + H_{cw}; \qquad (14)$$

which are given by

$$H_{c} = t_{v} \sum_{\substack{i,j \ (i,j) \leq C \\ i \neq j}}^{X} C_{i}^{y} C_{j}; \qquad (15)$$

$$H_{w} = \bigvee_{w} C_{i}^{y}c_{i} t_{w} C_{i}^{y}c_{j}; \quad (16)$$

$$H_{CW} = t_{CW} C_{X_{L}}^{Y} C_{X_{L}} C_{X_{L}}^{Y} + C_{X_{L}}^{Y} C_{X_{L}} C_{X$$

+
$$c_{X_{R};y}^{y} c_{X_{R}+1;y}$$
 + $c_{X_{R}+1;y}^{y} c_{X_{R};y}$: (17)

with $X_L = L_c + 1$ and $X_R = L_s + L_c$. Here H_c is the Ham iltonian for the nite regions C on the sample, H_w the Ham iltonian for the sem i-in nite regions W, and H_{cw} the coupling between the regions C and W. Two hopping parameters t_w ; t_{cw} and one parameter for uniform potential $_w$ are introduced for the wide band system. If $t_w = t_{cw} = t_c$ and $_w = 0$, the Ham iltonian (13) is exactly the same as the original Ham iltonian (1), which is the system we want to solve. How ever, as we explain below, we take a lim it t_w ; t_{cw} ; $_w$! 1 under certain conditions (conditions (24) and (25)). We call this lim it wide band lim it since the band width in the region W becomes in nity in the lim it t_w ! 1.

W e expand the G reen's functions in H $_{cw}$ and H $_{u}$. The retarded G reen's function for the wide band system (13) in the HF approximation is written as,

$$G^{r}() = H_{t} \sim (W)^{r}() \sim (HF) + i : (18)$$

Here H_t is the H am iltonian in a matrix form corresponding to H_t = H_s + H_s + H_c, \sim ^(HF) the self-energy in the HF approximation for the system (13)

$$\sim_{i,i}^{(HF)} = \frac{X}{U_{i,j}} - \frac{1}{2} d \operatorname{Im} \mathcal{G}_{j,j}^{r} () K ; (19)$$

$$\sim_{i;j(i \in j)}^{(HF)} = \frac{U_{i;j}}{1}^{Z} d \operatorname{Im} G_{i;j}^{r}(); \qquad (20)$$

where i; j 2 S, and $^{\sim (w\,)r}$ the retarded self-energy due to the sem i-in nite region W . An element $^{\sim (w\,)r}_{\ xy;x^0y^0}$ is non-zero only when x = x^0 = X $_{\rm L}$ or x = x^0 = X $_{\rm R}$. The non-zero elements are given by

$$\sum_{X \ y; X \ y^{0}}^{(w)r} () = \frac{t_{Cw}^{2}}{t_{w}} \sum_{n}^{X} () \sum_{n}^{X} (() = \frac{t_{Cw}^{2}}{t_{w}} \sum_{n}^{X} () \sum_{$$

where $X = X_L$ or X_R . The size of matrices in (18) is nite, $(I_s + 2L_c)L_y$ $(L_s + 2L_c)L_y$. We use the tilde to denote that they are the G reen's function and the selfenergy not for the original system but for the wide band system.

In the sem i-in nite regions W we take the wide band lim it. In this lim it the self-energy $^{(w)r}$ becomes independent of and the non-zero elements of $^{(w)r}$ are equal to

$$\sum_{\substack{X \ y; X \ y^{0}}}^{(w)r} = t, \qquad \sum_{n}^{X} (y) \ n \ (y^{0}) \ t, \qquad n \qquad (22)$$

This lim it is obtained by taking the lim it,

$$t_w; t_{cw}; w ! 1;$$
 (23)

while keeping

$$t_{cw}^2 = t_w = t_{v}; \qquad (24)$$

$$_{w} = t_{w} = = t_{v}$$
: (25)

(W hen = 0, we do not need to introduce w.)

A similar idea to use an energy independent self-energy can be seen in m any papers, for example, Refs. 31 and 41. Two important di erences from previous works are:

W e keep non-interacting regions up to a length $\rm I_c$ on both sides of the sample to reduce artifacts of taking the wide band lim it.

The self-energy for the wide band region is chosen so that electrons at = are not scattered at the boundaries between C and W . This makes it easier to reduce the artifacts.

The self-energy (22) in the wide band lim it is equal to the self-energy at = for the original system , i.e., the self-energy (21) with $t_w = t_{rw} = t_1$ and w = 0. This m eans that electrons at the Ferm i energy = are not scattered at the boundaries between the regions C and W .W hen electron-electron interaction is neglected, the Landauer conductance for the wide band system is exactly the same as that for the original Landauer system since the self-energy only at = is relevant for the conductance in non-interacting system s. W hen we take account of the electron-electron interaction, the conductances for the wide band system and for the original system are no longer the same, because electrons below the Ferm i energy a ect the motion of electrons at the Ferm i energy through the HF self-energy. To reduce such artifacts of taking the wide band lim it on the calculated conductance, we keep non-interacting regions up to a length L_c on both sides of the sam ple. W e expect that the artifacts of taking the wide band lim it decrease as L_c increases, and they are nally removed in the limit $L_c ! 1$.

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The absence of boundary scattering for electrons at = is important for the e ciency in removing the artifacts. If electrons near = are scattered strongly at the two boundaries, resonant states due to the boundary scattering can be form ed near = . In this case, the G reen's function G^r () at the Ferm ienergy shows larger

uctuation as a function of I_c , and we need to simulate system s with longer L_c to remove the artifacts. On the other hand, our choice m inim ize the boundary scattering of electrons near the Ferm i energy, that makes it easier to reduce the artifacts of taking the wide band lim it.

By taking the wide band lim it, the self-energy $^{(w)r}$ becomes independent of .We de nean e ective Ham iltonian by

$$H^{(e)r} = H_t + {}^{(w)r} + {}^{(HF)}:$$
 (26)

Then the Green's function (18) is written as

$$G^{r}() = H^{(e)r} + i$$
 (27)

N ote that $H^{(e)}r$ is not a H erm itian m atrix but is a com – plex sym m etric m atrix since H t and $^{(HF)}$ are real sym – m etric m atrices and $^{(W)r}$ is a com plex sym m etric m a-trix. The e ective H am iltonian has right and left eigenvectors

$$H^{(e)} \dot{\mathbf{r}}_n \dot{\mathbf{i}} = q_n \dot{\mathbf{r}}_n \dot{\mathbf{i}}, \qquad (28)$$

$$hl_n \mathbf{H}^{(e)r} = hl_n \mathbf{y}_h \mathbf{i}$$
(29)

Here q_h is an eigenvalue, which is complex in general. Since the elective Hamiltonian is a complex symmetric matrix, the transpose of the corresponding right eigenvector is the left eigenvector,

$$hl_n j = jr_n i^{>}$$
: (30)

For convenience, we impose the following normalization conditions.

$$hl_n j_{m} i = n_{m} : \qquad (31)$$

Then they satis es the com pleteness relation,

$$\begin{array}{c}
X \\
jr_n \, ihl_n \, j=1: \quad (32)
\end{array}$$

By using eigenvalues q_h and right eigenvectors $jr_n i$, the retarded G reen's function is expressed as^{23,42}

$$G_{i;j}^{r}() = \frac{X}{a_{h} + ib_{h} + i}$$
 (33)

Here a_n and (b_n) are the real part and the imaginary part of the eigenvalue, $q_h = a_n$ is b_h , and $(j) = hjjr_n i$.

To calculate the self-energy $^{\sim\,(H\,F\,)}$, we need to perform the integral of the imaginary part of the retarded G reen's function $_{\rm Z}$

$$J_{i;j}(; c) = d \operatorname{Im} G_{i;j}^{r}():$$
 (34)

For a moment, we introduce a cuto parameter $_{c}$. We will take the lim it $_{c}$! 1 later. By using the expression

$$J_{i;j}(; c) = \begin{array}{c} X \\ Re[n(i)_{n}(j)][n()_{n}(c)] \\ n \\ + Im[n(i)_{n}(j)]ln \frac{\cos n(c)}{\cos n(c)}; \end{array}$$
(35)

where n () (2 [=2 =2]) is de ned by

$$_{n}$$
 () = Tan¹ $\frac{a_{h}}{b_{h}}$: (36)

For the second term in (35), we should not take the lim it $_{\rm c}$! 1 before taking the sum mation over n because of the logarithm ic divergence

$$\ln [\cos_{n} (c_{c})] = \ln_{c} + \ln (b_{n} + c_{c}) + O(c_{c}^{-1}): (37)$$

The logarithm is divergence disappears when we take the sum mation over n because (32) im plies

$$Im [n (i) n (j)] = 0:$$
(38)

Therefore, in the lim it $_{\rm c}$! 1 we have

$$J_{i;j}(; 1) = \begin{array}{c} X & h & i \\ Re[n(i)_{n}(j)]_{n}() + \frac{1}{2} \\ & \\ + Im[n(i)_{n}(j)] ln & \frac{\cos n()}{b_{n} +} \end{array}; (39)$$

Thus we calculate the self-energy from the eigenvalues and the right eigenvectors of $H^{\sim\,(e~)}$ without performing numerical integration.

Finally the num erical in plem entation of the wide band m ethod is sum marized. First we prepare an initial matrix for $^{\rm (H\,F)}$. Then we calculate the eigenvalues and eigenvectors by diagonalizing the e ective H am iltonian H^{(e)r}. From the eigenvalues and right eigenvectors, we calculate the self-energy $^{\rm (H\,F)}$, (19) and (20), by using (39). We continue this self-consistent iteration until $^{\rm (H\,F)}$ converges with enough precision. (To ensure convergence, we have used \the m ethod of potentialm ixing".¹⁷) A fler convergence, we calculate the conductance g(L_c) for the wide band system by using the expression (6), where G^{rrs} () is substituted for G^{rrs} (). We expect that the conductance g (L_c) for the wide band system in the lim it L_c ! 1,

$$g = \lim_{L_c! \ 1} g(L_c)$$
: (40)

In the case of 1D system (x6) we extrapolate $g(L_c)$ by using an empirical tting function. In the case of 2D system (x7) we make L_c large enough so that the artifacts of the wide band limit can be negligible to a good approximation.



Fig. 3. The conductance $g(L_c)$ for the wide band system calculated with the wide band m ethod in 1D in the rst order perturbation is shown as a function of L_c . We set K = 0.5, = 0.0, and U = 0.5. The dotted lines are the t of (45) to the data with $L_c = [11;30]$. The t deviates from the numerical data when L_c is much sm aller than this range. The solid line indicates the conductance for the original system, g $0.9785e^2$ =h, obtained from (44).

6. Application to a 1D system

6.1 System

Here we calculate the Landauer conductance in a 1D system, i.e. $L_y = 1$, described by the Hamiltonian (1). We suppose that the hopping parameter is uniform in the system and set it unity as a unit of energy, $t_s = t_s = t_s = 1$. We also suppose that two electrons are interacting only when they occupy the nearest neighbor sites,

$$U_{x,x^{0}} = \begin{array}{c} U & (\text{if } x^{0} = x \quad 1) \\ 0 & (\text{otherw ise}): \end{array}$$
(41)

Transport phenom ena in this model was previously studied in Refs. 34{36,43. We set the positive background charge K = 0.5 and the Ferm i energy = 0, which corresponds to half-lling. Since we use the rst order perturbation or the self-consistent HF approximation the electron-electron interaction should be weak, so we set U = 0.5.

6.2 In the rst order perturbation

First we calculate the Landauer conductance in the rst order perturbation to test the wide band method. Since the system studied here is very simple, the conductance in the rst order perturbation for the original Landauer system (1) can be calculated analytically without making use of the wide band method. By comparing the numerical results of the wide band method with the analytical results, we test the wide band method.

The self-energy in the rst order perturbation for the original system (1) is obtained by replacing G^{r} in (8) and (9) with the G reen's function G_{0}^{r} for the non-interacting

H am iltonian H₀. The rst order H artree term is zero because the uniform negative charge of the electrons cancels with the uniform positive charge in the background. The rst order exchange term at = 0 is given by

$$^{(1st)}_{x;x+1} = \frac{U}{-}$$
 (1 x L_s 1): (42)

From this self-energy, we obtain the conductance in the rst order perturbation.W hen $\rm L_s$ is odd, we have a perfect transm ission,

$$g = \frac{e^2}{h} \qquad (L_s : odd): \qquad (43)$$

For even L_s we have

$$g = \frac{e^2}{h} \frac{2(1 + U =)}{(1 + U =)^2 + 1}^2 \quad (L_s : even): \quad (44)$$

W hen U = 0:5 and L_s is even, we nd g ' 0:9785 \hat{e} =h.

We have also calculated the conductance in the $\,$ rst order perturbation by using the wide band method. The numerical result in the $\,$ rst order perturbation has been obtained by stopping the self-consistent iteration after just one iteration. When $\rm L_s$ is odd, the conductance is always e^2 =h independent of $\rm L_c$ and $\rm L_s$. When $\rm L_s$ is even, the conductance is reduced from e^2 =h. As shown in Fig. 3, g(L_c) oscillates as a function of $\rm L_c$ when $\rm L_s$ is even.

To rem ove the artifacts of taking the wide band lim it, we need to extrapolate the conductance $g(L_c)$ to L_c ! 1. The extrapolation has been done by using an empirical thing function of the form,

$$g(L_c) = g + a \frac{\cos(L_c)}{L_c^{\gamma}}:$$
 (45)

Here g, a, and y are tting parameters. We expect that the asymptotic value g is equal to the conductance for the original system .By tting numerical data with $L_c = [11;30]$, we have found g $0.9785e^2 = h$ for any even L_s in the range $L_s = [2;16]$. The estimates of a and y weakly depend on the range of L_c used for the t. On the other hand, the estimate of the asymptotic value g is stable against the change of the range of L_c .

The asymptotic value g $0.9785e^2=h$ for even L_s estimated with the wide band m ethod is in good agreement with the analytical result (44) for the original Landauer geometry. The di erence of the conductance is of order 10⁸ to 10⁶ in units of $e^2=h$. The good agreement indicates that the wide band m ethod works well to estimate the conductance g by extrapolating the conductance tance g (L_c) for the wide band system to L_c ! 1.

6.3 In the self-consistent Hartree-Fock approximation

W e have then calculated the conductance in 1D in the HF approximation with the wide band method. W hen L_s is odd, we have found $g(L_c) = e^2 = h$ for any L_c . W hen L_s is even, the conductance is reduced from $e^2 = h$. W e extrapolated the conductance for each even L_s to L_c ! 1 by using the thing function (45), as in the case of the

rst order perturbation. Som e num erical data and the corresponding ts are shown in Fig. 4. From the t, we have obtained the asymptotic value g for each even L_s .



Fig. 4. The conductance $g(L_c)$ for the wide band system calculated with the wide band method in 1D in the HF approximation is shown as a function of L_c . We set K = 0.5, = 0.0, and U = 0.5. The dotted lines are the t of (45) to the data with $L_c = [11;30]$. The t deviates from the numerical data when L_c is much sm aller than this range. The solid line indicates the conductance for the original system with $L_s = 2$, g $0.9749e^2 = h$, obtained from (46) and (47). There is no solid line for $L_s = 16$ since it is too di cult for us to calculate the conductance for the original system with $L_s = 16$ in the HF approximation.

Even in the HF approximation it is not impossible to calculate the conductance g for the original system without using the wide band method. So far we have calculated g only for $L_s = 2$. The Hartree term $\binom{(HF)}{x_{1x}}$ is zero when = 0 because of the particle-hole symmetry. The exchange self-energy $\binom{(HF)}{12}$ for $L_s = 2$ is a solution of⁴⁴

1
$$v = U \frac{v^2}{2v^2} 1 \frac{1}{2v} \operatorname{Tan}^1 \frac{2v}{v^2} \frac{1}{1} + \frac{1}{v}$$
; (46)

with v = 1 ${}^{(HF)}_{1;2}$. From this equation we nd ${}^{(HF)}_{1;2}$ 0:1733 for U = 0:5. By using a form ula for the conductance

$$g = \frac{e^2}{h} \frac{2(1 \qquad (HF))}{(1 \qquad (HF))^2 + 1} \frac{\#_2}{(1 \qquad (HF))^2 + 1}; \qquad (47)$$

we ndg 0.9749^2 =h for L_s = 2 and U = 0.5. This value of the conductance is indicated with a solid line in Fig. 4. The di erence between this value and that estimated with the wide band m ethod is of order 10 $^{8}e^{2}$ =h, indicating that the wide band m ethod works well.

6.4 Length dependence of the conductance { com parison of num erical results

Figure 5 shows the L_s dependence of the conductance within the rst order perturbation and within the HF approximation.For a reference, the conductance calculated with the embedding method by R.A.Molina and J.L. Pichard⁴⁵ is also shown. In the embedding method, the electron-electron interaction is treated exactly, hence it is thought that the calculated conductance is also exact.



Fig. 5. L_s dependent oscillation of the conductance g in 1D. The conductance g in the rst order perturbation and in the HF approximation are shown as well as that of the embedding method.⁴³ W e set K = 0.5, = 0.0, and U = 0.5. The data calculated by the embedding method were provided by R.A. Molina and J.-L.P ichard.⁴⁵ The lines are a guide to the eye only.

In all three cases, the perfect conductance $g = e^2 = h$ is obtained when L_s is odd, and the conductance is reduced from it when L_s is even. This even-odd oscillation was found in Ref. 43. A similar parity oscillation in the Hubbard chain was reported in Ref. 30.

W ithin the storder perturbation, the conductance is independent of L_s for all even L_s . How ever, the result of the embedding method, which is thought to be exact, indicates that the conductance for even L_s decreases when L_s increases. The conductance for even L_s in the HF approximation also shows that the conductance decreases with increasing L_s . So we ind a qualitative agreement between the behavior of the conductance in the HF approximation and that of the embedding method. Furthermore, the results indicate that the HF approximation quantitatively.

7. Application to a 2D system

7.1 System

The application of the wide band method is not restricted to 1D system s. Here we apply it to a 2D system, i.e., a square system ($L_s = L_y$). The hopping parameter is supposed to be uniform and set it unity as a unit of energy, $t_s = t_{2} = t_{2} = 1$. We consider the nearest neighbor electron-electron interaction in the sample region,

$$U_{i;j} = \begin{array}{c} U & (\text{if } (i;j) \text{ is a n n pair}) \\ 0 & (\text{otherw ise}): \end{array}$$
(48)

In our simulation, we set the strength of electron-electron interaction U = 0.5. We set the chemical potential = 0 and the positive charge K = 0.5, which corresponds to half-lling.



Fig. 6. The conductance $g(L_c)$ for the wide band system calculated with the wide band m ethod in 2D in the rst order perturbation for (a) $L_s = 8$ and (b) $L_s = 16$ is shown as a function of L_c . We set K = 0.5, = 0.0, and U = 0.5. The dotted lines are a guide to the eye only. The solid lines indicates the conductance g for the original system obtained from (49) and (50) without using the wide band m ethod.

7.2 In the rst order perturbation

First we have calculated the conductance within the rst order perturbation to test the wide band m ethod in 2D as it has been tested in 1D in x6.

W ithin the storder perturbation, we can calculate the conductance without using the wide band method since the self-energy ^(1st) in the storder perturbation for the original Landauer system is obtained as follows. The Hartree contribution is zero since the positive background charge compensate the negative charge of electrons. The exchange contribution is given by

$$\sin k_y^{(n)}(y+1)$$
; (50

where $k_y^{(n)} = n = (L_s + 1)$. We have calculated ^(1st) by taking the sum mation over n in (49) and (50) numerically, and then have calculated the corresponding conductance g.

We have also calculated the conductance making use of the wide band method in the rst order perturbation. Figure 6 shows the L_c dependence of the conductance $g(L_c)$ for the wide band system s with sample size $L_s = 8$ and $L_s = 16$. For a reference, the conductance g calculated from (49) and (50) is also shown with the solid



Fig. 7. The conductance $g(L_c)$ for the wide band system calculated with the wide band method in 2D in the HF approximation for (a)L_s = 8 and (b)L_s = 16 is shown as a function of L_c.We set K = 0.5, = 0.0, and U = 0.5.The dotted lines are a guide to the eye only.

line. The gure indicates that $g(L_c)$ uctuates around the value g and the uctuation becomes smaller when L_c increases. It is reasonable to assume that the in u-ence of the wide band lim it is, to a good approximation, negligible when $L_c = 30$,

$$g g(L_c = 30)$$
: (51)

We have found that the di erences between the value g obtained from (49) and (50) and g($L_c = 30$) are of order 10⁵ to 10³ in units of e²=h for $L_s = [2;16]$. This indicates that the wide band m ethod also works well in 2D.

7.3 In the self-consistent Hartree-Fock approximation

We have then calculated the conductance in 2D with the wide band method in the HF approximation. Figure 7 shows the L_c dependence of the conductance $g(L_c)$ for the wide band system swith sample size $L_s = 8$ and $L_s = 16$. The L_c dependence of $g(L_c)$ is qualitatively similar to that in the rst order perturbation. We again assume that the in uence of the wide band limit is negligible when $L_c = 30$.

In the range $L_c = [21;30]$, the uctuation of $g(L_c)$ is of order 10⁻³ in units of $e^2 = h \cdot A$ ssum ing that $g(L_c)$ is uctuating around the asymptotic value g, we can consider the amplitude of the uctuation as a precision of g in the wide band method.

7.4 L_s dependence of the conductance

Figure 8 shows L_s dependence of the conductance in the rst order perturbation and in the HF approximation in 2D. For a reference, the value $N_c e^2$ =h corresponding



Fig. 8. L_s dependence of the conductance g in 2D in the rstorder perturbation and in the HF approximations.We set K = 0:5, = 0:0, and U = 0:5. For a reference, the conductance corresponding to the perfect transmission N ce²=h is also shown. (At = 0, N c = L s in the 2D strip imposed xed boundary conditions in the transverse direction.) The dotted and dashed lines are a guide to the eye only.

to a perfect transm ission, with N $_{\rm c}$ being the number of propagating channels, is also show n. The conductance in the HF approximation tends to be smaller than that in the rst order perturbation as it is in 1D

8. Sum m ary and D iscussion

We have developed a new numerical method to calculate the Landauer conductance through an interacting electron system at zero temperature in the rst order perturbation or in the self-consistent HF approximation. A troublesome numerical integration is avoided by taking a wide band lim it. We can remove the artifacts of taking the wide band lim it by increasing the length of non-interacting region L_c kept on both sides of the sam – ple.We have applied it to 1D and 2D interacting system s.

The method does not require much CPU time, so it permits us to accumulate many samples in studying interacting disordered system s. Simulation in the presence of disorder is left for future.

The wide band m ethod has an advantage that the dim ensionality is not restricted to one. This m ethod can be useful when studying various quantum transport phenom ena not only in interacting disordered systems but also in quantum dots, quantum point contacts, quantum nanow ires, atom ic chains, and so on. It is possible to consider spin degree of freedom. It is also possible to take account of other e ects, such as spin-orbit coupling and a m agnetic eld, by generalizing the wide band m ethod. In the presence of such e ects, the e ective H am iltonian m ight be no longer a com plex sym m etric m atrix. W hen it is not a com plex sym m etric m atrix, we need to calculate not only the right eigenvectors but also the left eigenvectors.

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Appendix: G reen's functions for sem i-in nite leads and som e related m atrices

In this appendix, the retarded G reen's function for sem i-in nite leads and some related matrices are shown explicitly. We suppose that the leads are described by the Ham iltonian (3) and coupled with a sample by (4).

F irst we calculate the retarded G reen's function g^r () for the isolated lead at the left (x 0). In particular, the in portant elements are those at the surface of the lead, i.e., the elements $g^r_{0y;0y^0}$ (). The eigenfunctions and eigenvalues of the lead are written as

$$k_{x};n(x;y) = \frac{1}{2} \sin [k_{x}(x \ 1)]_{n}(y); (A \ 1)$$

$$E_{k_x;n} = 2t_x \cos k_x + t_x = (A - 2)$$

where

$$_{n}(y) = \frac{1}{2(L_{y} + 1)} \sin k_{y}^{(n)} y ; \quad (A 3)$$

=
$$2 \cos k_y^{(n)}$$
: (A 4)

Here k_x (2 [0;]) is the wave number in the x-direction, and $k_y^{(n)} = n = (L_y + 1) \cdot U$ sing them we have

$$g_{0y;0y^{0}}^{r}(\cdot) = \frac{1}{t_{n=1}} \sum_{n=1}^{t_{y}} (y) (y^{0}) = \frac{1}{t_{n}} \sum_{n=1}^{t_{y}} (x - t_{n})$$

Here the function (z_n) is given by

n

$$(\mathbf{z}_{n}) = \underbrace{\begin{array}{c} \mathbf{z}_{n} \\ \mathbf{z}_{n} \\$$

Sim ilarly, the G reen's function for the other lead at the right (x $L_s + 1$) is obtained as

$$g_{L_{s}+1y;L_{s}+1y^{0}}^{r}(x) = \frac{1}{t_{x}} \frac{X^{y}}{n} (y) (y^{0}) = \frac{1}{t_{x}} \frac{X^{y}}{n} (y^{0}) (x) (x^{0}) = \frac{1}{t_{x}} (x^{0}) (x^{0}) (x^{0}) (x^{0}) = \frac{1}{t_{x}} (x^{0}) (x^{0}) (x^{0}) (x^{0}) (x^{0}) = \frac{1}{t_{x}} (x^{0}) (x^{0$$

A transverse mode n is a propagating mode if $j = t_n$, j 2 and an evanescent mode otherwise. The Ferm i wave number $k_F^{(n)}$ (0 k_n) of the propagating mode n in the x-direction is determined by

$$e^{ik_{F}^{(n)}} = \frac{z_{n}}{2}$$
 i $1 - \frac{z_{n}^{2}}{4}$; (A 8)

with $z_n = =t_n$.

W hen calculating the Landauer conductance the sem iin nite leads and the sam ple are coupled by (4). In the G reen's function method the e ects of the lead are taken account in terms of the self-energy.^{23,38} The retarded self-energy $_{xy;x^0y^0}^{(1)r}$ due to the leads becomes non-zero at the surfaces of the sam ple, i.e., when $x = x^0 =$ 1 or $x = x^0 = L_s$. The non-zero elements are dened by $_{1y;1y^0}^{(1)r}() = t_s^2 g_{0y;0y^0}^r()$ and $_{L_sy;L_sy^0}^{(1)r}() =$ $t_s^2 g_{L_s+1y;L_s+1y^0}^r()$. Using the expression (A 5) we have

where $X = 1 \text{ or } L_s$.

The L_y L_y matrices ^(L) and ^(R), which appear in the Landauer formula (6), are deneed by ^(L)_{yy⁰}() = i $r_{1y_{f}1y^{0}}()$ $a_{1y_{f}1y^{0}}()$ and ^(R)_{yy⁰}() = i $r_{L_{s}y_{f}L_{s}y^{0}}()$ At = we have ^(L,R)_{yy⁰}() = $\frac{2t\zeta_{s}^{2}X}{t}$ a_{n} (y) r_{n} (y⁰) sin $k_{F}^{(n)}$: (A 10)

Here the sum m ation is taken over propagating m odes.

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